

A Novell Hall Magnetometer Using Dynamic Offset Cancellation [†]

Siya Lozanova, Svetoslav Noykov, L. Altunyan, A. Ivanov and Chavdar Roumenin *

Institute of Robotics at Bulgarian Academy of Sciences, Sofia, Bulgaria; lozanovasi@abv.bg (S.L.); snoykov@gmail.com (S.N.); email3@email.com (L.A.); email4@email.com (A.I.)

* Correspondence: roumenin@bas.bg; Tel.: +359-2-870-3361

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Abstract: A novel Hall magnetometer using dynamic offset cancellation principle is presented. It consists from a single triangular silicon plate with three contacts and interface electronics. The proposed dynamic offset-cancelling measurement cycle includes three states. During each state, an external circuit is switched to the plate contacts in a certain way. This way, the direction of current flow through the Hall plate is changed from phase to phase. At the same time, the output voltage is measured. After averaging the obtained three voltages per a measurement cycle, the offset voltage cancelled and this way the offset-free Hall voltage is obtained. The obtained offset reduction factor is very promising, reaching 120–130. The Hall device sensitivity is about 25 V/AT.

Keywords: dynamic offset cancellation; hall magnetometer; sensor interface electronics

1. Introduction

The very important key characteristic of the Hall sensors is the offset voltage V_{off} , which is its output signal in the absence of magnetic field [1–3]. It depends on power supply, temperature, mechanical stress and sometimes it is larger than the Hall voltage $V_H(B)$. Some efforts to reduce the initial offset V_{off} by hardware consists of orthogonally coupling of two or more matched symmetrical Hall plates [2]. But, after applying this method, the residual offset is large since the matched Hall plates are not identical. An alternative effort to reduce the initial offset V_{off} , is the spinning current method [3–5], or “dynamic offset cancellation” [1]. In the spinning-current method, the direction of current flow in a single symmetrical Hall plate is made to spin around an axis through the center of the Hall plate. At the same time, the output voltage is sampled at the Hall contact pair which is perpendicularly oriented to the current flow [2]. The very common Hall sensors are four terminal devices [1,6–10], where one pair of opposite terminals serves as drive contacts and the other pair as sense contacts; consequently Hall sensors can be operated in two [1] or four [3] different modes. During an offset cancelling measurement cycle, the drive current is spatially rotated through these modes and the corresponding output signals are averaged [1,6–10].

This paper presents a novel Hall magnetometer using dynamic offset cancellation principle, based on a single equilateral triangular n-Si plate with three contacts only. The functions, necessary for obtaining the useful Hall signal and cancelling the offset, are performed by proper interface electronics. Moreover, this device is characterized by high spatial resolution due to the small number of Hall plate contacts (three only).

2. The Hall Plate Design and Magnetometer Operation Principle

The Hall plate consists of a semiconductor n-Si structure in the form of an equilateral triangle, Figure 1. The magnetosensitivity is about 25 V/AT. On the surface of the substrate, near the vertices of the triangle, three n^+ -contacts, C_1 , C_2 , and C_3 are positioned.

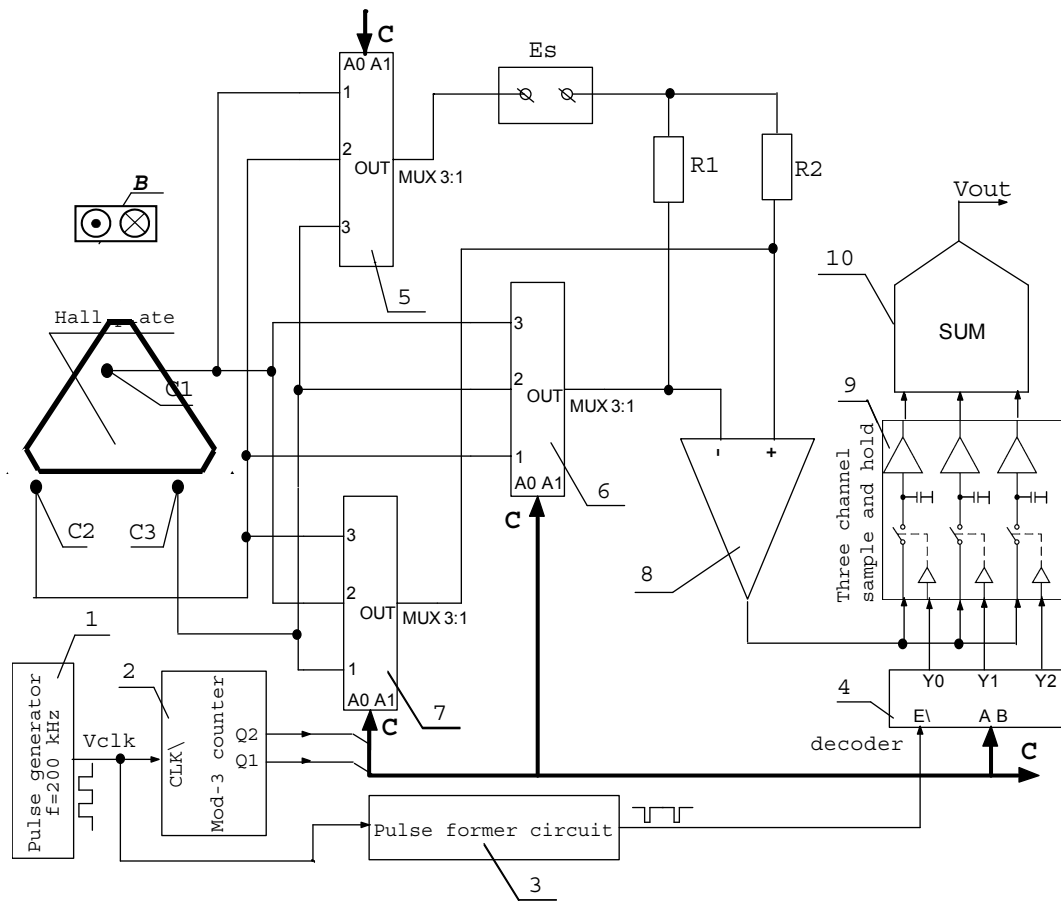


Figure 1. Block diagram of the magnetometer based on an equilateral triangular Hall element.

The dynamic offset-cancelling measurement cycle includes three consecutive states, shown in Figure 2a–c. We shall call them 0° state, 120° state and 240° state respectively. In Figure 2a–c, for the convenience of analysis, the Hall element is represented by a model of three connected in triangle resistors— r_1 , r_2 and r_3 . As is shown, during each state, an external circuit is connected to the plate contacts in a certain way. Such external circuit comprise the power supply with terminals $-V_s$ and $+V_s$ and the resistor network R_1 – R_2 ($R_1 = R_2 = R$). One terminal of R_1 as well as one terminal of R_2 is connected to the power supply terminal $+V_s$. The other terminal of R_1 as well as the other terminal of R_2 is switched to a certain pair of adjacent plate contacts. To the third plate contact, the power supply terminal $-V_s$ is switched. Between the terminals Lo and Hi , the sensor output voltage V_{out} is measured. In general, V_{out} consists of two parts, namely the magnetic field dependent Hall voltage $V_H(B)$ and the offset voltage V_{off} :

$$V_{out} = V_H(B) + V_{off} \quad (1)$$

The Hall plate is fed with constant current as the value of external resistors R_1 and R_2 many times exceed the value of r_1 , r_2 and r_3 .

The first state of the measurement cycle (0° state) is shown in Figure 2a. The resistor R_1 is switched to contact

C_2 , the resistor R_2 is switched to contact C_3 , and the power supply terminal $-V_s$ is switched to contact C_1 . For an ideal Hall plate, the resistances of r_1 , r_2 , and r_3 are equal, i.e., $r_1 = r_2 = r_3 = r$. The resistors r_1 , r_2 , R_1 and R_2 form Wheatstone bridge. In the absence of magnetic field, the output voltage measured between the terminals Lo and Hi will be zero, because the bridge is balanced. In the presence of magnetic field, the Lorentz force $F_L = q\mathbf{V}_{dr} \times \mathbf{B}$ deflects the moving carriers laterally; q is the electron charge and \mathbf{V}_{dr} is the velocity of the carriers. As a result, in the vicinity of the contacts C_2 and C_3 additional charges are generated, resulting in appearing of Hall voltage between the contacts

Hi and Lo. The Hall voltage is proportional to the magnitude of the magnetic field B , and its sign depend on the direction of the magnetic field B .

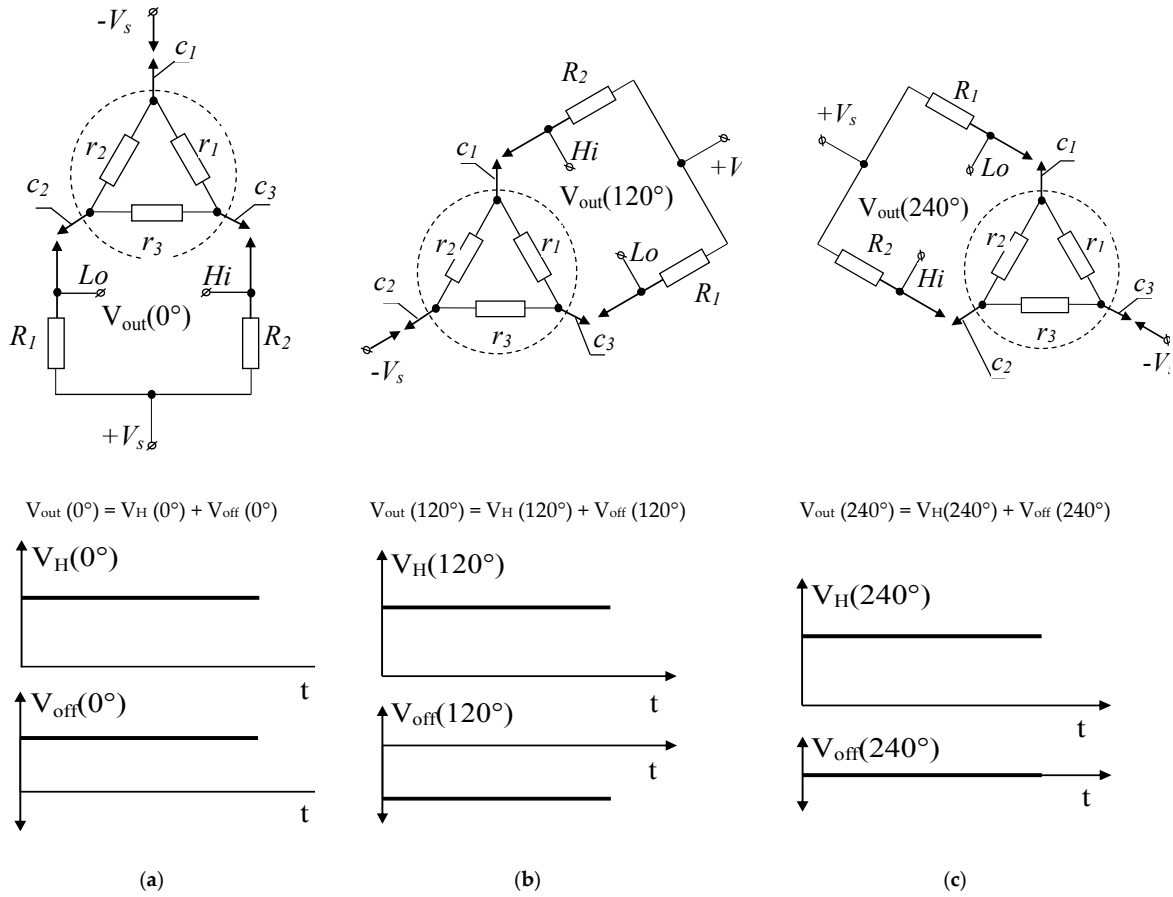


Figure 2. Measurement cycle for dynamic offset cancellation: (a) state 1; (b) state 2; (c) state 3.

Assume that an imbalance, for example due to a mechanical stress, occurs such that the region between the contacts c_1 and c_2 shows a resistance smaller than the rest of the plate, i.e., $r_1 = r_3 = r$; $r_2 = r - \Delta r$. In such case, in absence of magnetic field B , ($B = 0$), the output voltage V_{out} between the contacts Lo and Hi will be different from zero as the bridge (r_1 – r_2 – R_1 – R_2) is not balanced due to $r_1 \neq r_2$. To the terminal Lo , the resistor r_2 is connected, corresponding to the substrate region with resistance $r - \Delta r$, and to the terminal Hi , the resistor r_1 is connected, corresponding to the substrate region with resistance r . Then, the offset voltage $V_{off}(0^\circ)$ will be measured, Figure 2a. In the presence of magnetic field B ($B \neq 0$), the Hall voltage V_H between the contacts Lo and Hi appeared, which is added to the offset voltage $V_{off}(0^\circ)$. In particular direction of the magnetic field, the Hall voltage $V_H(0^\circ)$ will have the same sign as the offset voltage $V_{off}(0^\circ)$, as is shown in Figure 2a.

The second state of the measurement cycle (120° state) is shown in Figure 2b. Actually, switching contacts during the transition from the first to second state is carried out in such a way that the external circuit rotated virtually in the Hall element plane around its center to an angle 120° from its initial position, Figure 2b. In such case, the bridge r_2 – r_3 – R_1 – R_2 is not balanced due to $r_2 \neq r_3$. To the terminal Lo , the resistor r_3 is connected, corresponding to the substrate region with resistance r , and to the terminal Hi , the resistor r_2 is connected, corresponding to the substrate region with resistance $r - \Delta r$. This means that the measured between contacts Lo and Hi offset voltage $V_{off}(120^\circ)$ will have the same value but opposite sign compared to the measured offset voltage $V_{off}(0^\circ)$ during the first state of the measurement cycle (0° state) shown in Figure 2a. As can be seen from the scheme, the measured Hall voltage $V_H(120^\circ)$ between the output contacts Hi and Lo will have the same sign compared to the measured Hall voltage $V_H(0^\circ)$ during the first state (0° state).

The third state of the measurement cycle (240° state) is shown in Figure 2c. Actually, switching contacts during the transition from the first to third state is carried out in such a way that the external circuit rotated virtually in the Hall element plane around its center to an angle 240° from its initial position, Figure 2c. In such case, the bridge (r_1 – r_3 – R_1 – R_2) is balanced due to $r_1 = r_3$. This means that the measured between the contacts Lo and Hi offset voltage V_0 (120°) will be zero, i.e., V_0 (120°) = 0. As can be seen from the scheme, the measured Hall voltage V_H (120°) between the output contacts Hi and Lo will have the same sign compared to the measured Hall voltages V_H (0°) and V_H (120°) during the first state (0° state) and second state (120° state).

In the end, the obtained voltages from each of the three consecutive states from the current measurement cycle are summed. This way, the useful Hall signal triples but the offset voltages are cancelled in most cases:

$$V_{out} = (V_0(0^\circ) + V_H) + (V_0(120^\circ) + V_H) + (V_0(240^\circ) + V_H) = 3V_H + V_{res} \quad (2)$$

where V_{res} is so-called residual plate offset, which is very low.

3. Interface Circuitry and Results

The block diagram of the sensor interface circuit is shown in Figure 1. Block 1, “Pulse Generator”, clocks the mod-3 counter (Block 2) by pulse sequence with proper frequency. Block 2 carries out the following functions: (1) generates a sequence to control the switching over the contacts of the Hall plate to the power supply E_s and the resistor network— R_2 ; and (2) takes part in the formation of proper pulses to control Block 9, “Three channel sample-and-hold”. Based on the control sequence generated by Block 2, the multiplexers 5, 6 and 7 directly switch over the contacts of the microdevice to the power supply E_s and the resistor network R_1 – R_2 . Block 8 comprises a precise instrumentation amplifier. To obtain offset compensated value of the sensor signal, the output of Block 8 is passed to Block 9, “Three channel sample-and-hold”. Block 4 feeds proper sampling pulses to the sampling inputs of Block 9, so that the outputs of the sample-and-hold circuits hold the output voltages obtained from the current measurement cycle. The summer 10 sums these three voltages. Thus, the obtained Hall voltages from each of the three consecutive states from the current measurement cycle, are summed but the corresponding offset voltages are cancelled in most cases. The offset reduction factor is about 120–130. Despite the fact that the new device uses discrete realization, the obtained performance is promising for various applications in the robotics, automation, low-field magnetometry, navigation etc.

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Conflicts of Interest: The authors declare no conflict of interest.

References

1. Bilotti, A.; Monreal, G.; Vig, R. Monolithic magnetic Hall sensor using dynamic quadrature offset cancellation. *IEEE J. Solid State Circuits* **1997**, *32*, 829–836.
2. Munter, P. *Spinning-Current Method for Offset Reduction in Silicon Hall Plates*; Delf University Press: Delft, The Netherlands, 1992.
3. Sander, Ch.; Vecchi, M.; Cornils, M.; Paul, O. From Three-Contact Vertical Hall Elements to Symmetrized Vertical Hall Sensors with Low Offset. *Sens. Actuators A Phys.* **2016**, *240*, 92–102.
4. Munter, P. A low-offset spinning-current Hall plate. *Sens. Actuators A Phys.* **1990**, *22*, 743–746.
5. Steiner, R.; Maier, C.; Häberli, A.; Steiner, F.; Baltes, H. Offset reduction in Hall devices by continuous spinning current method. *Sens. Actuators A Phys.* **1998**, *66*, 167–172.
6. Taranow, S.G.; et al. Method for the Compensation of the Non-Equipotential Voltage in the Hall Voltage and Means for its Realization. German Patent No. 2333080, 1973.
7. Kaufmann, T. On the Offset and Sensitivity of CMOS-Based Five-Contact Vertical Hall Devices. Ph.D. Thesis, IMTEK, University of-Freiburg, 2013.
8. Vanha, R. *Rotary Switch and Current Monitor by Hall-Based Microsystems*; ETH Zurich: Zurich, Switzerland, 1999; ISBN 3-89649-446-5.

9. Bellekom, S. *Origins of Offset in Conventional and Spinning-Current Hall Plates*; Delft University Press: Delft, The Netherlands, 1998; p. 129, ISBN 90-407-1722-2.
10. Roumenin, C. Microsensors for magnetic field (Ch. 9). In *MEMS—A Practical Guide to Design, Analysis and Applications*; Korvink, J., Paul, O., Eds.; William Andrew Publishing: Norwich, NY, USA, 2006; pp. 453–523, ISBN 0-8155-1497-2.



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